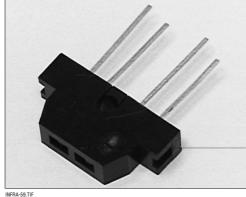
Reflective Sensor

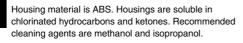
FEATURES

- Phototransistor output
- Focused for maximum response
- · Low profile housing



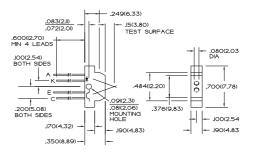
DESCRIPTION

The HOA0149 consists of an infrared emitting diode and an NPN silicon phototransistor encased side-byside on converging optical axes in a black thermoplastic housing. The phototransistor responds to radiation from the IRED only when a reflective object passes within its field of view. The HOA0149 employs plastic molded components. For additional component information see SEP8505 and SDP8405.



OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.010(0.25) 2 plc decimals ±0.020(0.51)



DIM_038.cdr



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Reflective Sensor

ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
IR EMITTER						
Forward Voltage	VF			1.6	V	I _F =20 mA
Reverse Leakage Current	I _R			10	μΑ	V _R =3 V
DETECTOR						
Collector-Emitter Breakdown Voltage	V _(BR) CEO	30			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector Dark Current	Iceo			100	nA	V _{CE} =15 V, I _F =0
COUPLED CHARACTERISTICS On-State Collector Current HOA0149-001	Ic(on)	1.0			mA	VcE=5 V, Ir=40 mA
Collector-Emitter Saturation Voltage	VCE(SAT)			0.4	V	I _C =125 μA, I _F =40 mA ⁽¹⁾
Rise And Fall Time	t _r , t _f		15	·	μs	Vcc=5 V, Ic=1 mA

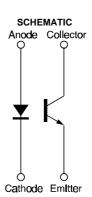
Notes
1. Test surface is a front surface mirror (polished aluminum, 85% reflectance) located 0.15 in.(3.80 mm) from the front surface of the

ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted)

Operating Temperature Range -40°C to 85°C -40°C to 85°C Storage Temperature Range Soldering Temperature (5 sec) 240°C IR EMITTER Power Dissipation 70 mW (1) 3 V

Reverse Voltage Continuous Forward Current 50 mA DETECTOR 30 V Collector-Emitter Voltage Emitter-Collector Voltage 70 mW (1) Power Dissipation



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Collector DC Current

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30 mA

Reflective Sensor

Fig. 1 IRED Forward Bias Characteristics

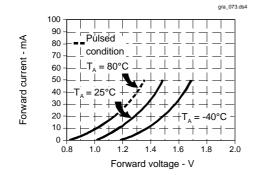


Fig. 2 Non-Saturated Switching Time vs Load Resistance gra_074.ds4

Load resistance - Ohms

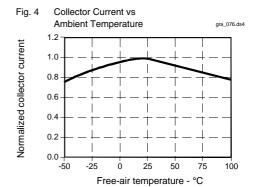
Fig. 3 Dark Current vs
Temperature

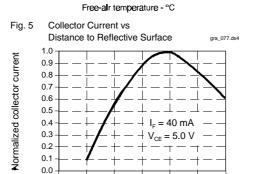
1000

VCE = 15 V
H = 0

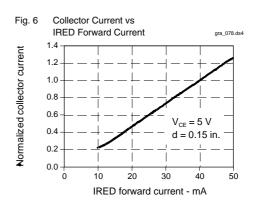
100

VCE = 15 V
H = 0





60



All Performance Curves Show Typical Values

0.10

0.15

Distance to reflective surface - inches

0.20

0.25

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0.1

-40

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